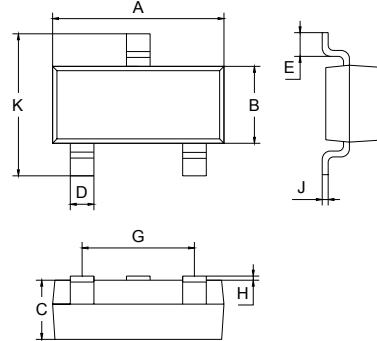


1. BASE
2. EMITTER
3. COLLECTOR

FEATURES

- Epitaxial planar die construction.
- Complementary PNP type available (MMBT3906).
- Collector Current Capability $I_{CM} = 200\text{mA}$.
- Collector-emitter Voltage $V_{CEO} = 40\text{V}$.



SOT-23		
Dim	Min	Max
A	2.70	3.10
B	1.10	1.50
C	1.0 Typical	
D	0.4 Typical	
E	0.35	0.48
G	1.80	2.00
H	0.02	0.1
J	0.1 Typical	
K	2.20	2.60
All Dimensions in mm		

APPLICATIONS

- General switching and amplification

ORDERING INFORMATION

Type No.	Marking	Package Code
MMBT3904	1AM	SOT-23

MAXIMUM RATING @ $T_a = 25^\circ\text{C}$ unless otherwise specified

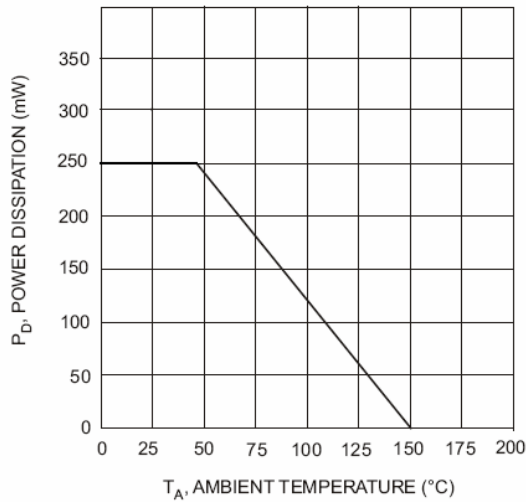
SYMBOL	PARAMETER	CONDITIONS	Value	UNIT
V_{CBO}	collector-base voltage	open emitter	60	V
V_{CEO}	collector-emitter voltage	open base	40	V
V_{EBO}	emitter-base voltage	open collector	6	V
I_C	collector current (DC)		100	mA
I_{CM}	peak collector current		200	mA
I_{BM}	peak base current		100	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25^\circ\text{C}$	250	mW
T_{stg}	storage temperature		-65 to +150	$^\circ\text{C}$
T_j	junction temperature		150	$^\circ\text{C}$
T_{amb}	operating ambient temperature		-65 to +150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

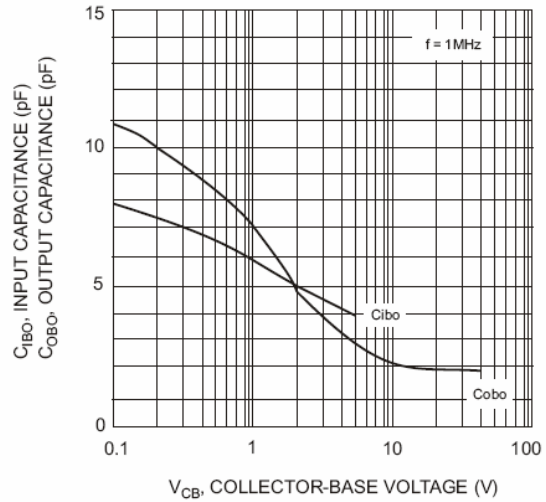
SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_{CBO}	collector cut-off current	$I_E = 0; V_{CB} = 30\text{ V}$	-	50	nA
I_{EBO}	emitter cut-off current	$I_C = 0; V_{EB} = 6\text{ V}$	-	50	nA
h_{FE}	DC current gain	$V_{CE} = 1\text{ V};$ $I_C = 0.1\text{ mA}$ $I_C = 1\text{ mA}$ $I_C = 10\text{ mA}$ $I_C = 50\text{ mA}$ $I_C = 100\text{ mA}$	60 80 100 60 30	- - 300 - -	
$V_{CE(sat)}$	collector-emitter saturation voltage	$I_C = 10\text{ mA}; I_B = 1\text{ mA}$	-	200	mV
		$I_C = 50\text{ mA}; I_B = 5\text{ mA}$	-	300	mV
$V_{BE(sat)}$	base-emitter saturation voltage	$I_C = 10\text{ mA}; I_B = 1\text{ mA}$	650	850	mV
		$I_C = 50\text{ mA}; I_B = 5\text{ mA}$	-	950	mV
C_{obo}	Output Capacitance	$I_E = I_e = 0; V_{CB} = 5\text{ V};$ $f = 1\text{ MHz}$	-	4	pF
C_{ibo}	Input Capacitance	$I_C = I_c = 0; V_{BE} = 500\text{ mV};$ $f = 1\text{ MHz}$	-	8	pF
f_T	transition frequency	$I_C = 10\text{ mA}; V_{CE} = 20\text{ V};$ $f = 100\text{ MHz}$	300	-	MHz
F	noise figure	$I_C = 100\text{ mA}; V_{CE} = 5\text{ V};$ $R_S = 1\text{ k}\Omega; f = 10\text{ Hz to } 15.7\text{ kHz}$	-	5	dB
Switching times (between 10% and 90% levels);					
t_d	delay time	$I_{Con} = 10\text{ mA}; I_{Bon} = 1\text{ mA};$ $I_{Boff} = -1\text{ mA}$	-	35	ns
t_r	rise time		-	35	ns
t_s	storage time		-	200	ns
t_f	fall time		-	50	ns

Note Pulse test: $t_p \leq 300\text{ ms}; d \leq 0.02$.

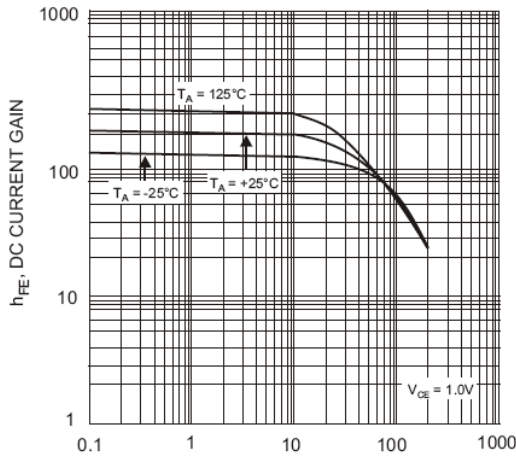
TYPICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified



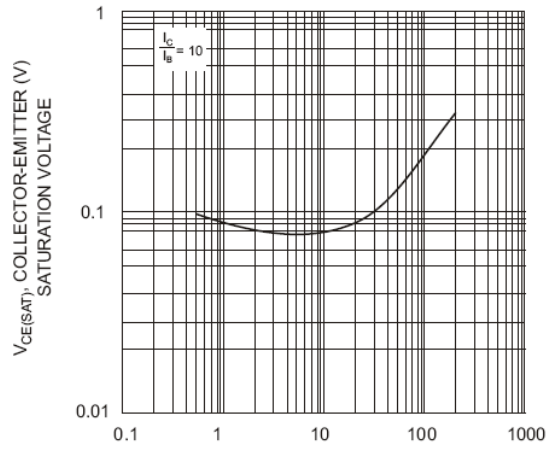
T_A, AMBIENT TEMPERATURE (°C)
Fig. 1, Max Power Dissipation vs Ambient Temperature



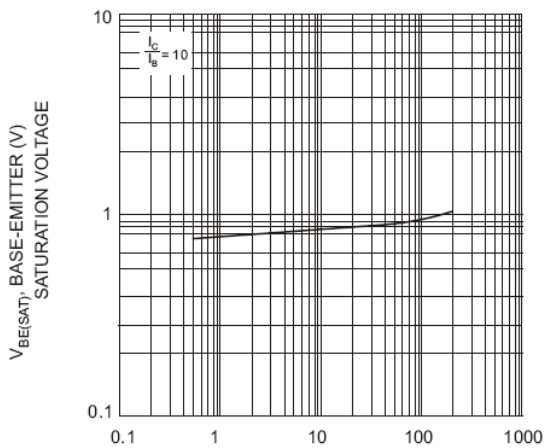
V_{CB}, COLLECTOR-BASE VOLTAGE (V)
Fig. 2, Input and Output Capacitance vs. Collector-Base Voltage



I_C, COLLECTOR CURRENT (mA)
Fig. 3, Typical DC Current Gain vs Collector Current



I_C, COLLECTOR CURRENT (mA)
Fig. 4, Typical Collector-Emitter Saturation Voltage vs. Collector Current



I_C, COLLECTOR CURRENT (mA)
Fig. 5, Typical Base-Emitter Saturation Voltage vs. Collector Current

Device	Package	Shipping
MMBT3904	SOT-23	3000/Tape&Reel

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Bipolar Transistors - BJT category](#):

Click to view products by [LGE manufacturer](#):

Other Similar products are found below :

[619691C](#) [MCH4017-TL-H](#) [MMBT-2369-TR](#) [BC546/116](#) [BC557/116](#) [BSW67A](#) [NJVMJD148T4G](#) [NTE123AP-10](#) [NTE153MCP](#) [NTE16](#)
[NTE195A](#) [NTE92](#) [C4460](#) [2N4401-A](#) [2N6728](#) [2SA1419T-TD-H](#) [2SA2126-E](#) [2SB1204S-TL-E](#) [2SC2712S-GR,LF](#) [2SC4731T-AY](#)
[2SC5488A-TL-H](#) [2SD2150T100R](#) [SP000011176](#) [2N2907A](#) [2N3904-NS](#) [2N5769](#) [2SC2412KT146S](#) [2SD1816S-TL-E](#) [CPH6501-TL-E](#)
[MCH4021-TL-E](#) [MJE340](#) [US6T6TR](#) [NJL0281DG](#) [732314D](#) [CPH3121-TL-E](#) [CPH6021-TL-H](#) [SZT1010T1G](#) [873787E](#) [IMZ2AT108](#)
[UMX21NTR](#) [MCH6102-TL-E](#) [NJL0302DG](#) [2N3583](#) [30A02MH-TL-E](#) [NSV40301MZ4T1G](#) [NTE13](#) [NTE26](#) [NTE282](#) [NTE323](#) [NTE350](#)